



Dual Common Cathode Schottky Rectifier

FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- Guardring for overvoltage protection
- High surge current capability
- Moisture sensitivity level: level 1, per J-STD-020
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

MECHANICAL DATA

Case: TO-263AB (D²PAK)

Molding compound, UL flammability classification rating 94V-0
Base P/N with suffix "G" on packing code - halogen-free
Base P/N with prefix "H" on packing code - AEC-Q101 qualified

Terminal: Matte tin plated leads, solderable per JESD22-B102

Meet JESD 201 class 1A whisker test

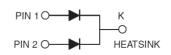
with prefix "H" on packing code meet JESD 201 class 2 whisker test

Polarity: As marked

Weight: 1.37 g (approximately)







TO-263AB (D²PAK)





MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T _A =25°ℂ unless otherwise noted)									
		MBRS	MBRS	MBRS	MBRS	MBRS	MBRS	MBRS	
PARAMETER	SYMBOL	1035	1045	1050	1060	1090	10100	10150	Unit
		СТ	СТ	СТ	СТ	СТ	СТ	СТ	
Maximum repetitive peak reverse voltage	V_{RRM}	35	45	50	60	90	100	150	V
Maximum RMS voltage	V_{RMS}	24	31	35	42	63	70	105	V
Maximum DC blocking voltage	V_{DC}	35	45	50	60	90	100	150	V
Maximum average forward rectified current	I _{F(AV)}				10				Α
Peak repetitive forward current (Rated VR, Square wave, 20KHz)	I _{FRM}	10			Α				
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	120			Α				
Peak repetitive reverse surge current (Note 1)	I _{RRM}	1			Α				
Maximum instantaneous forward voltage (Note 2) I_F = 5 A, T_J =25 $^{\circ}$ C I_F = 5 A, T_J =125 $^{\circ}$ C I_F = 10 A, T_J =25 $^{\circ}$ C	V _F	0.	70 57 80	0.	80 65 90	0.	85 75 95	0.88 0.78 0.98	>
I _F = 10 A, T _J =125°C			67		30 75		85	0.98	
Maximum reverse current @ rated VR T _J =25 °C		0.1							
T _J =100 ℃	I_R	1	5	1	0		-		mA
T _J =125 ℃		-			5				
Voltage rate of change (Rated V _R)	dV/dt	10000			V/µs				
Typical thermal resistance	$R_{\theta JC}$	2				°C/W			
Operating junction temperature range	TJ	- 55 to +150					οС		
Storage temperature range	T _{STG}	- 55 to +150			οС				

Note 1: $tp = 2.0 \mu s$, 1.0 KHz

Note 2: Pulse test with PW=300µs, 1% duty cycle

Document Number: DS_D1309057



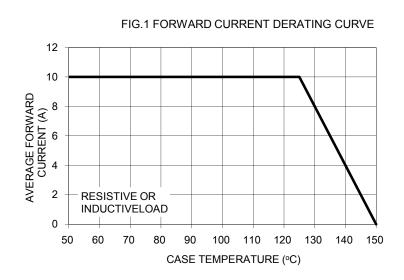
ORDERING INFORMATION					
PART NO.	AEC-Q101	PACKING CODE	GREEN COMPOUND	PACKAGE	PACKING
	QUALIFIED		CODE		
MBRS10xxCT	Prefix "H"	RN	Suffix "G"	D ² PAK	800 / 13" Paper reel
(Note 1)	FIGUX II	C0	Sullix G	D ² PAK	50 / Tube

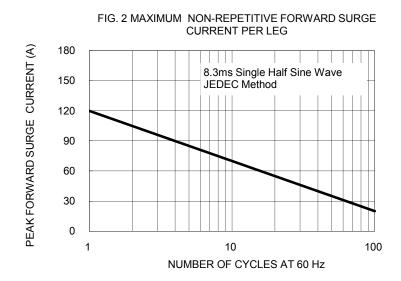
Note 1: "xx" defines voltage from 35V (MBRS1035CT) to 150V (MBRS10150CT)

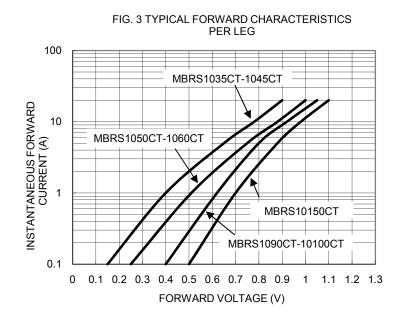
EXAMPLE						
PREFERRED P/N	PART NO.	AEC-Q101 QUALIFIED	PACKING CODE	GREEN COMPOUND CODE	DESCRIPTION	
MBRS1060CT RN	MBRS1060CT		RN			
MBRS1060CT RNG	MBRS1060CT		RN	G	Green compound	
MBRS1060CTHRN	MBRS1060CT	Н	RN		AEC-Q101 qualified	

RATINGS AND CHARACTERISTICS CURVES

(TA=25°C unless otherwise noted)







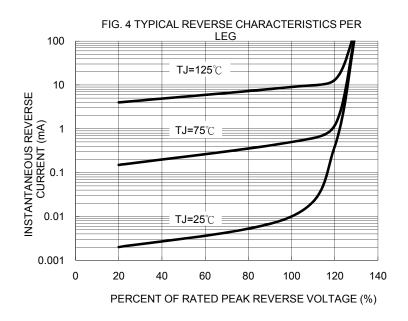
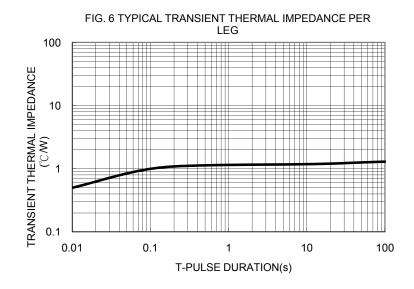


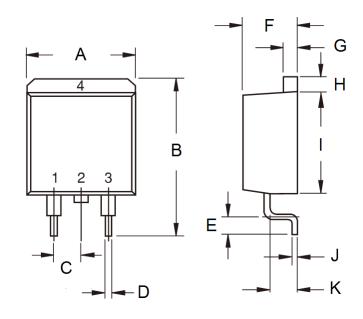




FIG. 5 TYPICAL JUNCTION CAPACITANCE 1000 900 f=1.0MHz 800 JUNCTION CAPACITANCE (pF) Vsig=50mVp-p 700 600 500 400 300 200 100 0 10 0.1 100 REVERSE VOLTAGE (V)

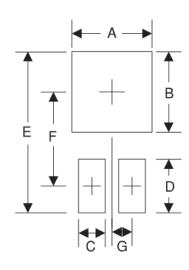


PACKAGE OUTLINE DIMENSIONS



DIM.	Unit	(mm)	Unit (inch)		
DIIVI.	Min	Max	Min	Max	
Α	-	10.5	-	0.413	
В	14.60	15.88	0.575	0.625	
С	2.41	2.67	0.095	0.105	
D	0.68	0.94	0.027	0.037	
Е	2.29	2.79	0.090	0.110	
F	4.44	4.70	0.175	0.185	
G	1.14	1.40	0.045	0.055	
Н	1.14	1.40	0.045	0.055	
Ì	8.25	9.25	0.325	0.364	
J	0.36	0.53	0.014	0.021	
K	2.03	2.79	0.080	0.110	

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
Α	10.8	0.425
В	8.3	0.327
С	1.1	0.043
D	3.5	0.138
E	16.9	0.665
F	9.5	0.374
G	2.5	0.098

MARKING DIAGRAM



P/N = Specific Device Code G = Green Compound

YWW = Date Code F = Factory Code

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